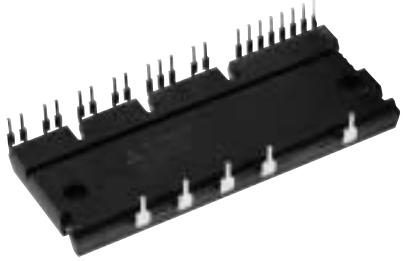


PS21869-A

TRANSFER-MOLD TYPE
INSULATED TYPE

PS21869



INTEGRATED POWER FUNCTIONS

600V/50A low-loss CSTBT inverter bridge for 3 phase
DC-to-AC power conversion

INTEGRATED DRIVE, PROTECTION AND SYSTEM CONTROL FUNCTIONS

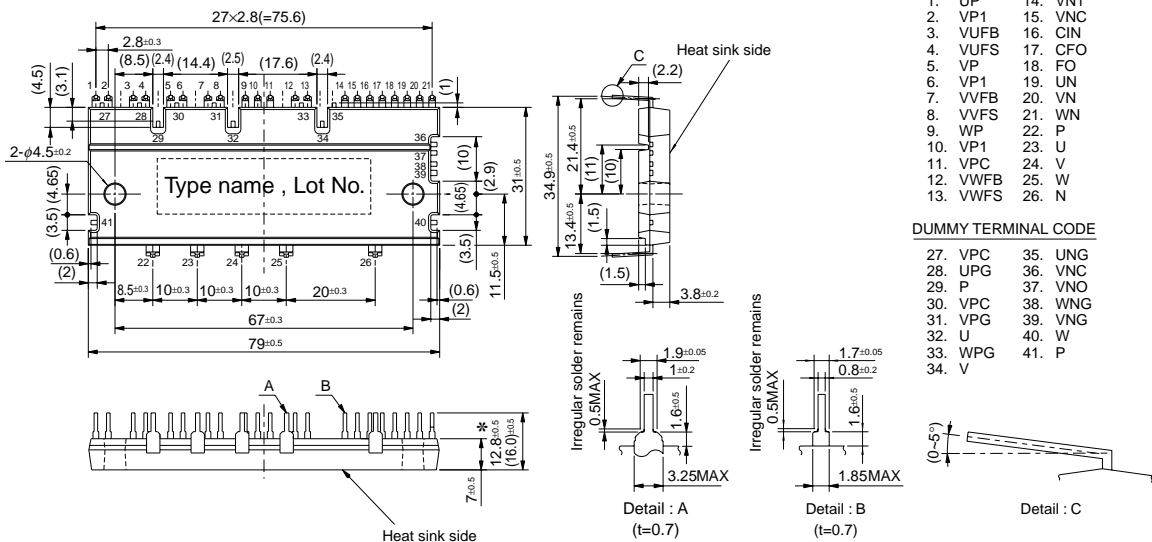
- For upper-leg IGBTs : Drive circuit, High voltage isolated high-speed level shifting, Control supply under-voltage (UV) protection.
- For lower-leg IGBTs : Drive circuit, Control supply under-voltage protection (UV), Short circuit protection (SC). (Fig.3)
- Fault signaling : Corresponding to an SC fault (Lower-side IGBT) or a UV fault (Lower-side supply).
- Input interface : 5V line CMOS/TTL compatible. (High Active)
- UL Approved : Yellow Card No. E80276

APPLICATION

AC100V~200V three-phase inverter drive for small power motor control.

Fig. 1 PACKAGE OUTLINES

Dimensions in mm



* -A : Long terminal type (16.0mm)

Fig. 2 INTERNAL FUNCTIONS BLOCK DIAGRAM (TYPICAL APPLICATION EXAMPLE)

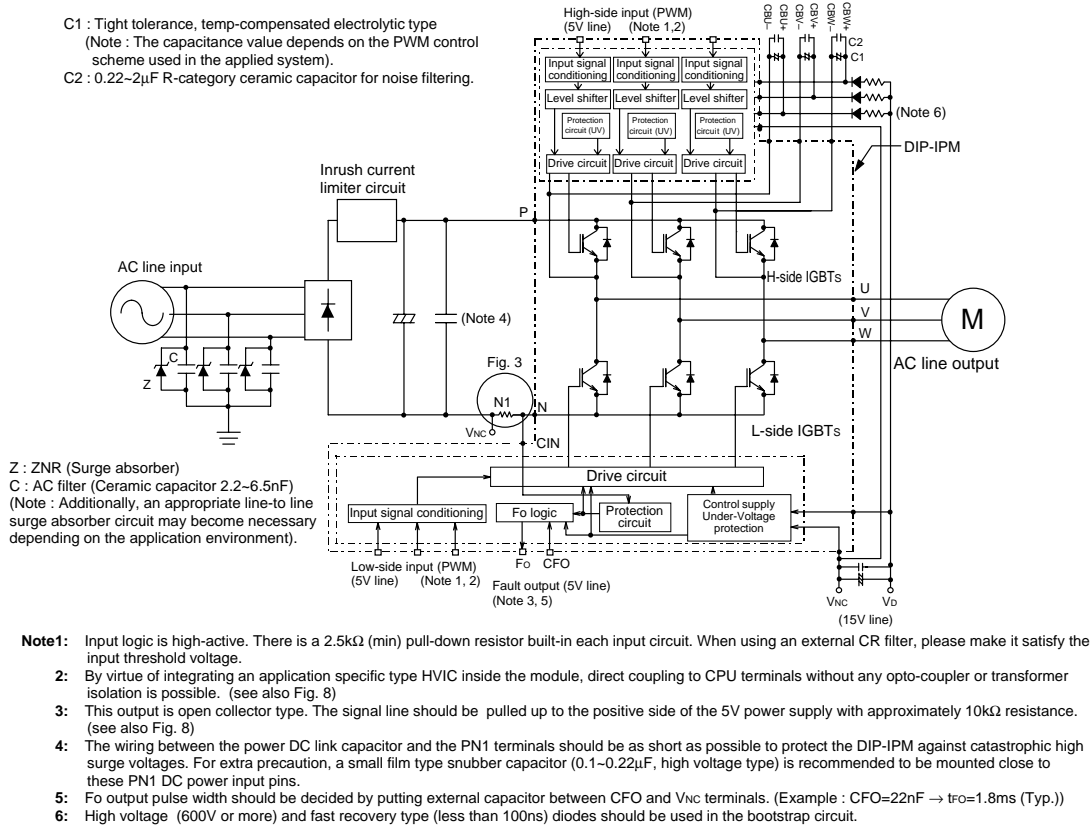
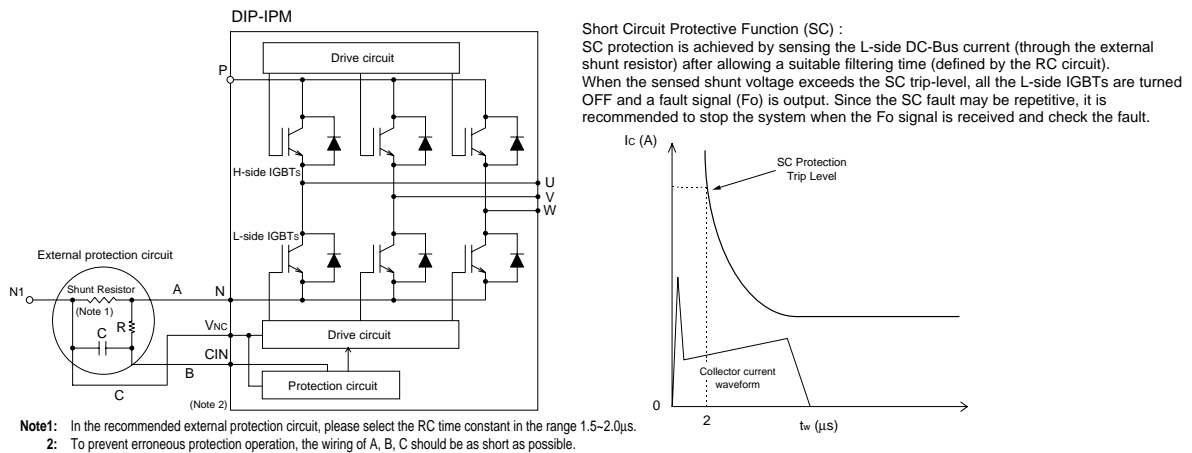


Fig. 3 EXTERNAL PART OF THE DIP-IPM PROTECTION CIRCUIT



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MAXIMUM RATINGS ($T_j = 25^\circ\text{C}$, unless otherwise noted)

INVERTER PART

| Symbol | Parameter | Condition | Ratings | Unit |
|--------------|------------------------------------|--|----------|------------------|
| VCC | Supply voltage | Applied between P-N | 450 | V |
| VCC(surge) | Supply voltage (surge) | Applied between P-N | 500 | V |
| VCEs | Collector-emitter voltage | | 600 | V |
| $\pm I_C$ | Each IGBT collector current | $T_f = 25^\circ\text{C}$ | 50 | A |
| $\pm I_{CP}$ | Each IGBT collector current (peak) | $T_f = 25^\circ\text{C}$, less than 1ms | 100 | A |
| PC | Collector dissipation | $T_f = 25^\circ\text{C}$, per 1 chip | 70.4 | W |
| T_j | Junction temperature | (Note 1) | -20~+125 | $^\circ\text{C}$ |

Note 1 : The maximum junction temperature rating of the power chips integrated within the DIP-IPM is 150°C ($T_f \leq 100^\circ\text{C}$) however, to ensure safe operation of the DIP-IPM, the average junction temperature should be limited to $T_{j(ave)} \leq 125^\circ\text{C}$ ($T_f \leq 100^\circ\text{C}$).

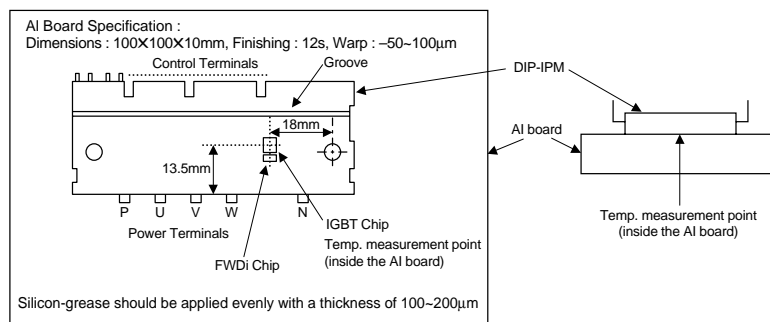
CONTROL (PROTECTION) PART

| Symbol | Parameter | Condition | Ratings | Unit |
|-----------------|-------------------------------|---|--------------------------|------|
| V _D | Control supply voltage | Applied between VP1-VPC, VN1-VNC | 20 | V |
| V _{DB} | Control supply voltage | Applied between VUFB-VUFS, VVFB-VVFS, VWFB-VWFS | 20 | V |
| V _{IN} | Input voltage | Applied between UP, VP, WP-VPC, UN, VN, WN-VNC | -0.5-V _D +0.5 | V |
| V _{FO} | Fault output supply voltage | Applied between FO-VNC | -0.5-V _D +0.5 | V |
| I _{FO} | Fault output current | Sink current at FO terminal | 1 | mA |
| V _{SC} | Current sensing input voltage | Applied between CIN-VNC | -0.5-V _D +0.5 | V |

TOTAL SYSTEM

| Symbol | Parameter | Condition | Ratings | Unit |
|------------------|--|---|----------|------------------|
| VCC(PROT) | Self protection supply voltage limit (short circuit protection capability) | V _D = 13.5~16.5V, Inverter part $T_j = 125^\circ\text{C}$, non-repetitive, less than 2 μs | 400 | V |
| T _f | Module case operation temperature | (Note 2) | -20~+100 | $^\circ\text{C}$ |
| T _{stg} | Storage temperature | | -40~+125 | $^\circ\text{C}$ |
| V _{iso} | Isolation voltage | 60Hz, Sinusoidal, AC 1 minute, connection pins to heat-sink plate | 2500 | V _{rms} |

Note 2 : T_f MEASUREMENT POINT



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**TRANSFER-MOLD TYPE
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THERMAL RESISTANCE

| Symbol | Parameter | Condition | Limits | | | Unit |
|-----------------------|--|-------------------------------------|--------|------|------|------|
| | | | Min. | Typ. | Max. | |
| R _{th(j-f)Q} | Junction to case thermal resistance (Note 3) | Inverter IGBT part (per 1/6 module) | — | — | 1.42 | °C/W |
| R _{th(j-f)F} | | Inverter FWDi part (per 1/6 module) | — | — | 2.00 | °C/W |

Note 3: Grease with good thermal conductivity should be applied evenly with about +100μm~+200μm on the contacting surface of DIP-IPM and heat-sink.

ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise noted)

INVERTER PART

| Symbol | Parameter | Condition | Limits | | | Unit |
|----------------------|--------------------------------------|--|-----------------------------------|---|------|------|
| | | | Min. | Typ. | Max. | |
| V _{CE(sat)} | Collector-emitter saturation voltage | V _D = V _{DB} = 15V I _C = 50A, T _j = 25°C V _{IN} = 5V I _C = 50A, T _j = 125°C | — | 1.50 | 2.00 | V |
| V _{EC} | FWDi forward voltage | T _j = 25°C, -I _C = 50A, V _{IN} = 0V | — | 1.70 | 2.20 | V |
| t _{on} | Switching times | V _{CC} = 300V, V _D = V _{DB} = 15V I _C = 50A, T _j = 125°C, V _{IN} = 0 ↔ 5V Inductive load (upper-lower arm) | 0.70 | 1.30 | 1.90 | μs |
| t _{tr} | | | — | 0.30 | — | μs |
| t _{c(on)} | | | — | 0.40 | 0.60 | μs |
| t _{off} | | | — | 2.00 | 2.60 | μs |
| t _{c(off)} | | | — | 0.65 | 0.90 | μs |
| I _{CEs} | | | Collector-emitter cut-off current | V _{CE} = V _{CEs} T _j = 25°C T _j = 125°C | — | — |

CONTROL (PROTECTION) PART

| Symbol | Parameter | Condition | Limits | | | Unit | |
|----------------------|---|--|--|------|------|------|----|
| | | | Min. | Typ. | Max. | | |
| I _D | Circuit current | V _D = V _{DB} = 15V V _{IN} = 5V | Total of V _{P1} -V _{PC} , V _{N1} -V _{NC} | — | — | 5.00 | mA |
| | | | V _{UFB} -V _{UFS} , V _{VFB} -V _{VFS} , V _{WFB} -V _{WFS} | — | — | 0.40 | mA |
| | | V _D = V _{DB} = 15V V _{IN} = 0V | Total of V _{P1} -V _{PC} , V _{N1} -V _{NC} | — | — | 7.00 | mA |
| | | | V _{UFB} -V _{UFS} , V _{VFB} -V _{VFS} , V _{WFB} -V _{WFS} | — | — | 0.55 | mA |
| V _{FOH} | Fault output voltage | V _{SC} = 0V, F _O circuit pull-up to 5V with 10kΩ | 4.9 | — | — | V | |
| V _{FOL} | | V _{SC} = 1V, I _{FO} = 1mA | — | — | 0.95 | V | |
| V _{SC(ref)} | Short circuit trip level | T _j = 25°C, V _D = 15V (Note 4) | 0.43 | 0.48 | 0.53 | V | |
| I _{IN} | Input current | V _{IN} = 5V | 1.0 | 1.5 | 2.0 | mA | |
| U _{VDt} | Supply circuit under-voltage protection | T _j ≤ 125°C | Trip level | 10.0 | — | 12.0 | V |
| U _{VDBr} | | | Reset level | 10.5 | — | 12.5 | V |
| U _{VDt} | | | Trip level | 10.3 | — | 12.5 | V |
| U _{VDr} | | | Reset level | 10.8 | — | 13.0 | V |
| t _{FO} | Fault output pulse width | C _{FO} = 22nF (Note 5) | 1.0 | 1.8 | — | ms | |
| V _{th(on)} | ON threshold voltage | Applied between UP, VP, WP-VPC, UN, VN, WN-VNC | 2.1 | 2.3 | 2.6 | V | |
| V _{th(off)} | OFF threshold voltage | | 0.8 | 1.4 | 2.1 | V | |

Note 4: Short circuit protection is functioning only at the low-arms. Please select the value of the external shunt resistor such that the SC trip-level is less than 85 A.

5: Fault signal is output when the low-arms short circuit or control supply under-voltage protective functions operate. The fault output pulse-width t_{FO} depends on the capacitance value of C_{FO} according to the following approximate equation : C_{FO} = 12.2 × 10⁻⁶ × t_{FO} [F].

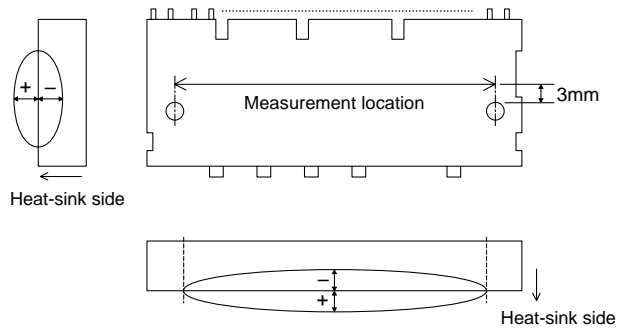
PS21869/-A

TRANSFER-MOLD TYPE
INSULATED TYPE

MECHANICAL CHARACTERISTICS AND RATINGS

| Parameter | Condition | | Limits | | | Unit |
|--------------------|---------------------|----------------------|--------|------|------|------|
| | | | Min. | Typ. | Max. | |
| Mounting torque | Mounting screw : M4 | Recommended 1.18 N-m | 0.98 | — | 1.47 | N-m |
| Weight | | | — | 65 | — | g |
| Heat-sink flatness | (Note 6) | | -50 | — | 100 | μm |

Note 6: Measurement point of heat-sink flatness



RECOMMENDED OPERATION CONDITIONS

| Symbol | Parameter | Condition | Limits | | | Unit |
|------------------------------------|---------------------------------|--|--------|------|------|------|
| | | | Min. | Typ. | Max. | |
| V _{CC} | Supply voltage | Applied between P-N | 0 | 300 | 400 | V |
| V _D | Control supply voltage | Applied between V _{P1} -V _{PC} , V _{N1} -V _{NC} | 13.5 | 15.0 | 16.5 | V |
| V _{DB} | Control supply voltage | Applied between V _{UFB} -V _{UFS} , V _{VFB} -V _{VFS} , V _{WFB} -V _{WFS} | 13.0 | 15.0 | 18.5 | V |
| ΔV _D , ΔV _{DB} | Control supply variation | | -1 | — | 1 | V/μs |
| t _{dead} | Arm shoot-through blocking time | For each input signal, T _f ≤ 100°C | 2 | — | — | μs |
| f _{PWM} | PWM input frequency | T _f ≤ 100°C, T _j ≤ 125°C | — | 5 | — | kHz |
| I _O | Allowable r.m.s. current | V _{CC} = 300V, V _D = 15V, f _c = 5kHz P.F = 0.8, sinusoidal T _j ≤ 125°C, T _f ≤ 100°C (Note 7) | — | — | 23 | Arms |
| P _{WIN} | Minimum input pulse width | ON (Note 8) | 300 | — | — | ns |
| V _{NC} | V _{NC} variation | between V _{NC} -N (including surge) | -5.0 | — | 5.0 | V |

Note 7 : The allowable r.m.s. current value depends on the actual application conditions.

8 : The input pulse width less than P_{WIN} might make no response.

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Fig. 4 THE DIP-IPM INTERNAL CIRCUIT

